

Notice of References Cited	Application/Control No. 10/618,024	Applicant(s)/Patent Under Reexamination VAUDO ET AL.	
	Examiner W. David Coleman	Art Unit 2823	Page 1 of 1

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*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
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	B	US-2002/0192507	12-2002	Dwilinski et al.	428/698
	C	US-			
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	J	US-			
	K	US-			
	L	US-			
	M	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
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NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
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	V	R. P. Vaudo et al., "GaN Boule Growth" A Pathway to GaN Wafers with Improved Material Quality", Physica Status Solidi (a), Published Online 10 December 2002, pp 494-497.
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.